# **BC847** series

45 V, 100 mA NPN general-purpose transistors

Rev. 12 — 24 October 2019

**Product data sheet** 

# 1. Product profile

#### 1.1. General description

NPN general-purpose transistors in a small SOT23 (TO-236AB), very small SOT323 (SC-70) or ultra small SOT883 (DFN1006-3) Surface-Mounted Device (SMD) plastic package.

**Table 1. Product overview** 

Type number[1]	Package		PNP complement	
	Nexperia	JEITA	JEDEC	
BC847	SOT23	-	TO-236AB	BC857
BC847A				BC857A
BC847B	_			BC857B
BC847C	_			BC857C
BC847W	SOT323	SC-70	-	BC857W
BC847AW	_			BC857AW
BC847BW				BC857BW
BC847CW	_			BC857CW
BC847AM	SOT883	SC-101	-	BC857AM
BC847BM				BC857BM
BC847CM				BC857CM

<sup>[1]</sup> Valid for all available selection groups.

#### 1.2. Features and benefits

- · General-purpose transistors
- SMD plastic packages
- Three different gain selections
- AEC-Q101 qualified

#### 1.3. Applications

General-purpose switching and amplification



#### 45 V, 100 mA NPN general-purpose transistors

### 1.4. Quick reference data

#### Table 2. Quick reference data

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	45	V
I <sub>C</sub>	collector current		-	-	100	mA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V;	110	-	800	
	h <sub>FE</sub> group A	I <sub>C</sub> = 2 mA	110	180	220	
	h <sub>FE</sub> group B		200	290	450	
	h <sub>FE</sub> group C		420	520	800	

# 2. Pinning information

**Table 3. Pinning information** 

Pin	Symbol	Descrition	Simlified outline	Graphic symbol
SOT23; SOT323				
1	В	base	3	С
2	E	emitter		
3	С	collector	1 2	B — E sym123
SOT883				,
1	В	base	1 🔲	С
2	E	emitter	2 3	
3	С	collector	Transparent top view	B— E
				sym123

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# 3. Ordering information

**Table 4. Ordering information** 

Type number	Package				
	Name	Description	Version		
BC847	TO-236AB	plastic surface-mounted package; 3	SOT23		
BC847A		leads			
BC847B					
BC847C					
BC847W	SC-70		SOT323		
BC847AW					
BC847BW					
BC847CW					
BC847AM	SC-101	lesdless ultra small plastic package;	SOT 883		
BC847BM		3 solder lands; body 1.0 x 0.6 x 0.5 mm			
BC847CM					

# 4. Marking

Table 5. Marking codes

Type number		Marking code
BC847	[1]	1H%
BC847A	[1]	1E%
BC847B	[1]	1F%
BC847C	[1]	1G%
BC847W	[1]	1H%
BC847AW	[1]	1E%
BC847BW	[1]	1F%
BC847CW	[1]	1G%
BC847AM		D4
BC847BM		D5
BC847CM		D6

<sup>[1] % =</sup> placeholder for manufacturing site code

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# 5. Limiting values

#### **Table 6. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	45	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	6	V
I <sub>C</sub>	collector current			-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p ≤ 1 ms</sub>		-	200	mA
I <sub>BM</sub>	peak base current	single pulse; t <sub>p ≤ 1 ms</sub>		-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C				
	SOT23		[1]	-	250	mW
	SOT323		[1]	-	200	mW
	SOT883		[2]	-	250	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.

### 6. Thermal characteristics

**Table 7. Thermal characteristics** 

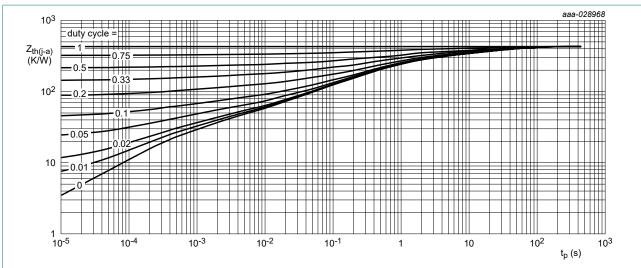
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air					
	SOT23		[1]	-	-	500	K/W
	SOT323		[1]	-	-	625	K/W
	SOT883		[2]	-	-	500	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB; single-sided copper; tin-plated and standard footprint.

<sup>[2]</sup> Device mounted on an PCB with 60 µm copper strip line, standard footprint.

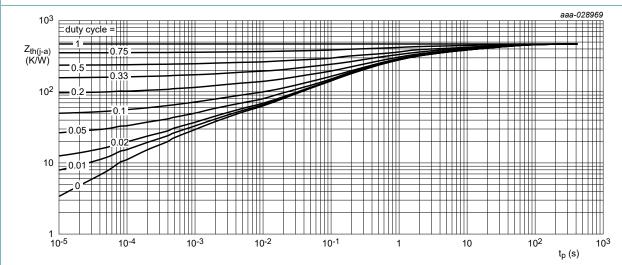
<sup>[2]</sup> Device mounted on an PCB with 60 µm copper strip line, standard footprint.

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FR4 PCB; single-sided copper; tin-plated and standard footprint

Fig. 1. SOT23: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided copper; tin-plated and standard footprint

Fig. 2. SOT323: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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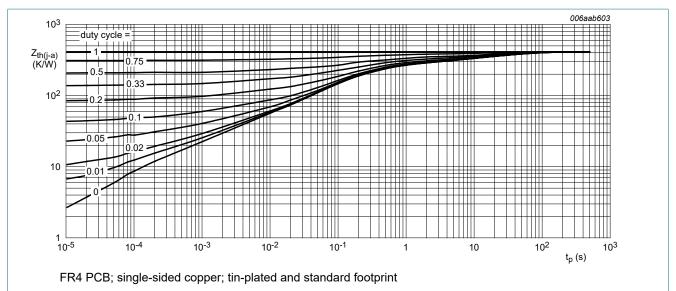


Fig. 3. SOT883: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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# 7. Characteristics

#### **Table 8. Characteristics**

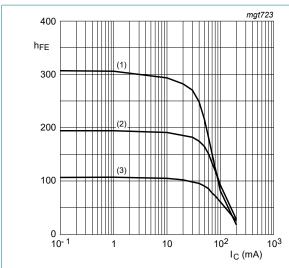
 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	I <sub>C</sub> = 100 μA; I <sub>E</sub> = 0 A		50	-	-	V
V <sub>(BR)CES</sub>	collector-emitter breakdown voltage	I <sub>C</sub> = 2 mA; V <sub>BE</sub> = 0 A		45	-	-	V
V <sub>(BR)EBO</sub>	emitter-base breakdown voltage	I <sub>C</sub> = 0 A; I <sub>E</sub> = 100 μA		6	-	-	V
I <sub>CBO</sub>	collector-base	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A		-	-	15	nA
	cut-off current	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$		-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 μA					
	h <sub>FE</sub> group A			-	170	-	
	h <sub>FE</sub> group B			-	280	-	
	h <sub>FE</sub> group C			-	420	-	
	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$		110	-	800	
	h <sub>FE</sub> group A			110	180	220	
	h <sub>FE</sub> group B			200	290	450	
	h <sub>FE</sub> group C			420	520	800	
$V_{CEsat}$	collector-emitter	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$		-	90	200	mV
	saturation voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	[1]	-	200	400	mV
$V_{BEsat}$	base-emitter saturation	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	[2]	-	700	-	mV
	voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	[2]	-	900	-	mV
$V_{BE}$	base-emitter voltage	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$	[2]	580	660	700	mV
		$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$		-	-	770	mV
f <sub>T</sub>	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}; f = 100 \text{ MHz}$		100	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	-	1.5	pF
C <sub>e</sub>	emitter capacitance	$V_{EB} = 0.5 \text{ V}; I_C = I_c = 0 \text{ A}; f = 1 \text{ MHz}$		-	11	-	pF
NF	noise figure	$I_C$ = 200 μA; $V_{CE}$ = 5 V; $R_S$ = 2 kΩ; $f$ = 1 kHz; $B$ = 200Hz		-	2	10	dB

<sup>[1]</sup> pulsed;  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ 

<sup>[2]</sup> V<sub>BE</sub> decreases by approximately 2 mV/K with increasing temperature

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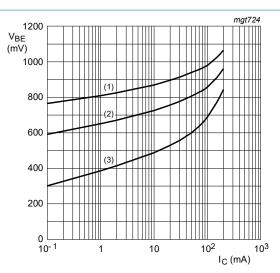


$$V_{CE} = 5 V$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. Group A: DC current gain as a function of collector current; typical values



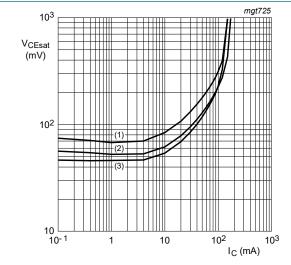
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. Group A: Base-emitter voltage as a function of collector current; typical values



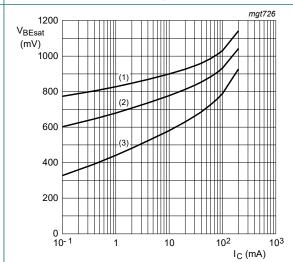
$$I_C/I_B = 20$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 6. Group A: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

(1) 
$$T_{amb} = -55$$
 °C

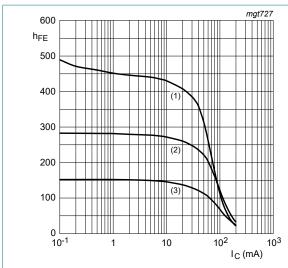
(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb}$$
 = 150 °C

g. 7. Group A: Base-emitter saturation voltage as a function of collector current; typical values

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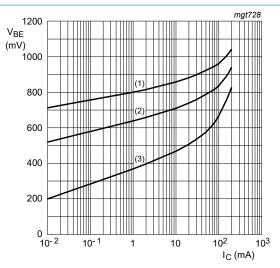
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Group B: DC current gain as a function of Fig. 8. collector current; typical values



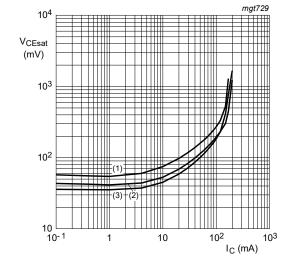
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Group B: Base-emitter voltage as a function of Fig. 9. collector current; typical values



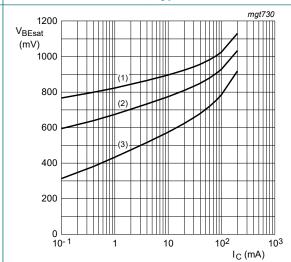
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb}$$
 = 150 °C

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

(1) 
$$T_{amb} = -55$$
 °C

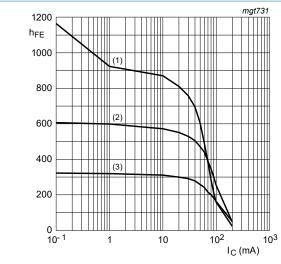
(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 10. Group B: Collector-emitter saturation voltage as Fig. 11. Group B: Base-emitter saturation voltage as a function of collector current; typical values

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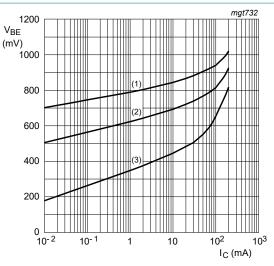
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55$$
 °C

Fig. 12. Group C: DC current gain as a function of collector current; typical values



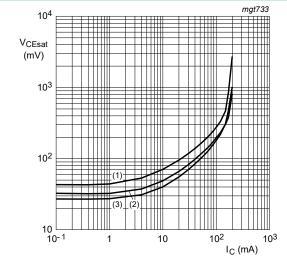
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 13. Group C: Base-emitter voltage as a function of collector current; typical values



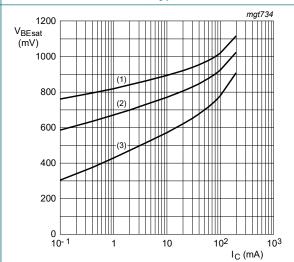
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb}$$
 = 150 °C

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 14. Group C: Collector-emitter saturation voltage as Fig. 15. Group C: Base-emitter saturation voltage as a function of collector current; typical values

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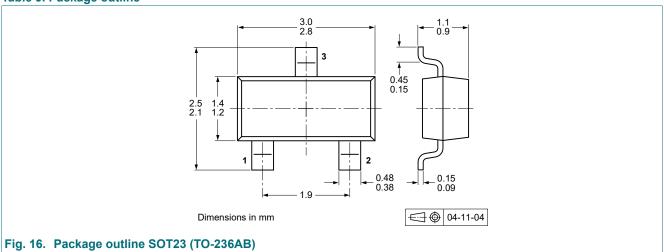
# 8. Test information

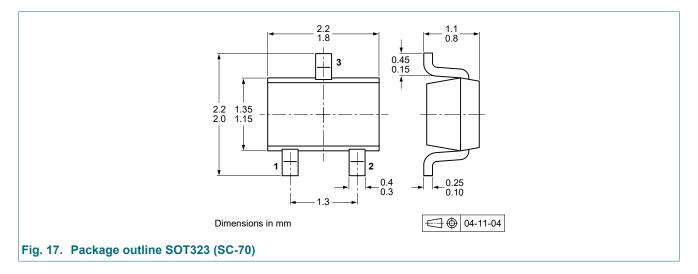
# 8.1. Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

# 9. Package outline

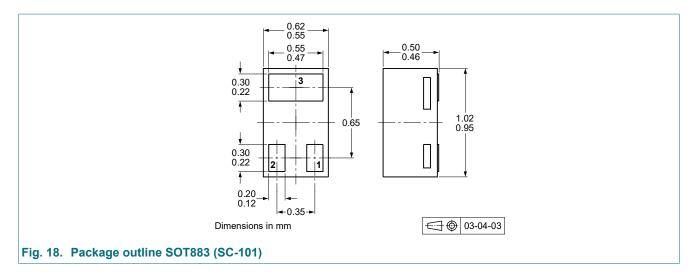
#### Table 9. Package outline





**Product data sheet** 

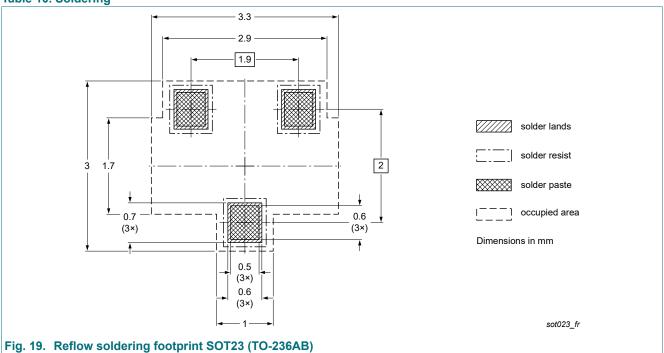
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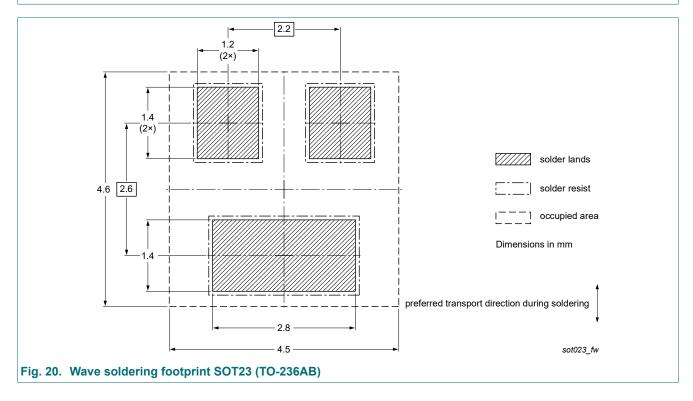


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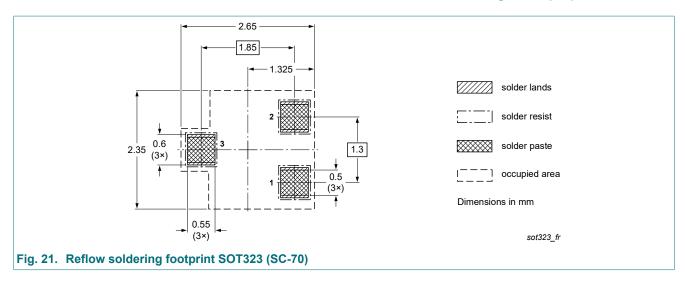
# 10. Soldering

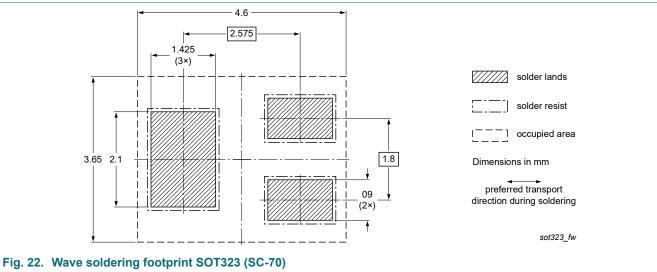


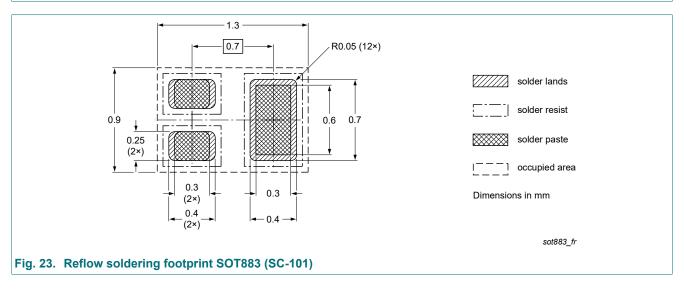




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### 45 V, 100 mA NPN general-purpose transistors

# 11. Revision history

#### **Table 11. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BC847_SER v.12	20191024	Product data sheet	-	BC847_SER v.11
Modifications:	Table 1: He	ader NPN complement correcte	d to PNP com	nplement
BC847_SER v.11	20181205	Product data sheet	-	BC847_SER v.10
BC847_SER v.10	20180302	Product data sheet	-	BC847_SER v.9
BC847_SER v.9	20140923	Product data sheet	-	BC847_SER v.8
BC847_SER v.8	20120820	Product data sheet	-	BC847_BC547_SER v.7
BC847_BC547_SER v.7	20081210	Product data sheet	-	BC847_BC547_SER v.6
BC847_BC547_SER v.6	20050519	Product data sheet	-	-

**Product data sheet** 

### 12. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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BC847\_SER

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For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 24 October 2019

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